

P-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Typ)
- 60	0.061 at V _{GS} = - 10 V	- 30	10
- 00	0.072 at V _{GS} = - 4.5 V	- 25	10

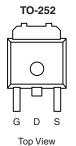
FEATURES

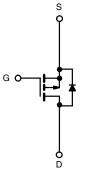
- TrenchFET[®] Power MOSFET
- 100 % UIS Tested

APPLICATIONS

Load Switch







P-Channel MOSFET

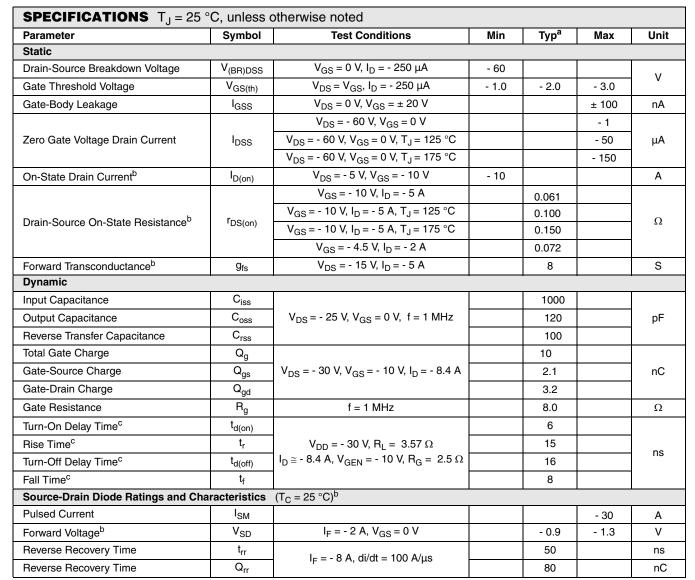
ABSOLUTE MAXIMUM RATINGS $T_C = 2$	25 °C, unless othe	rwise noted			
Parameter		Symbol	Limit	Unit	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current ($T_1 = 175 ^{\circ}C$)	T _C = 25 °C		- 30		
Continuous Drain Current $(T_j = T/5 C_j)$	T _C = 100 °C	I _D	- 25		
Pulsed Drain Current		I _{DM}	- 30	А	
Continuing Source Current (Diode Conduction)		۱ _S	- 20		
Avalanche Current		I _{AS}	- 20		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	7.2	mJ	
Maximum Dawar Dissinction	T _C = 25 °C	D	34 ^a	w	
Maximum Power Dissipation	T _A = 25 °C	P _D	4 ^b		
Operating Junction and Storage Temperature Range	•	T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
hundling to Anching b	t ≤ 10 sec	R _{thJA}	20	25	°C/W
Junction-to-Ambient ^D	Steady State		62	75	
Junction-to-Case		R _{thJC}	5	6	

Notes:

a. See SOA curve for voltage derating.

b. Surface Mounted on 1" x 1" FR-4 boad.



Notes:

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. Independent of operating temperature.

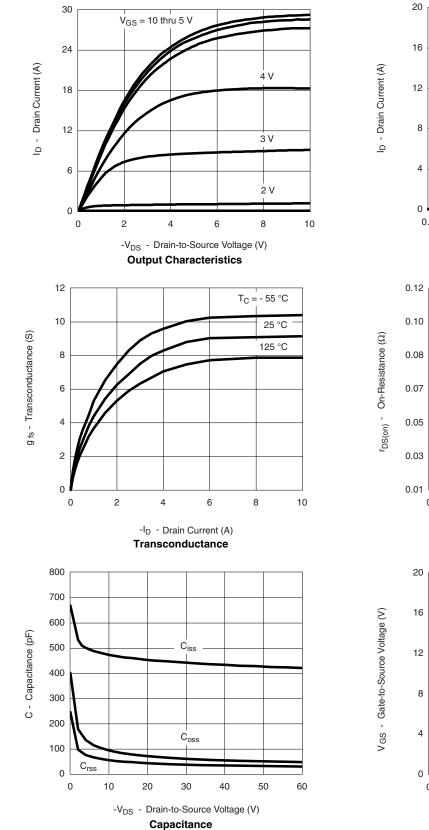
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



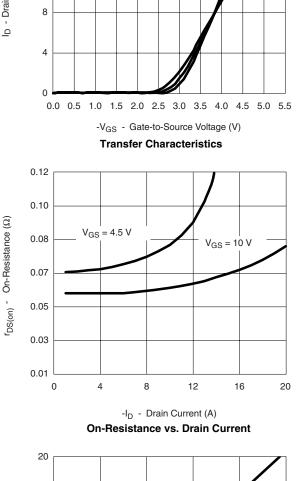
125 °C

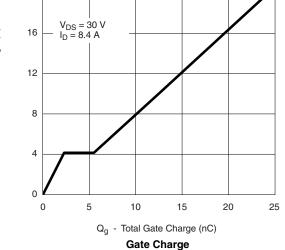
T_C = - 55 °C

1 25 °C



TYPICAL CHARACTERISTICS 25 °C unless noted





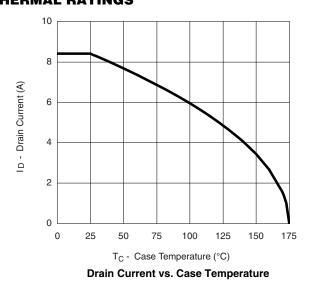
服务热线:400-655-8788

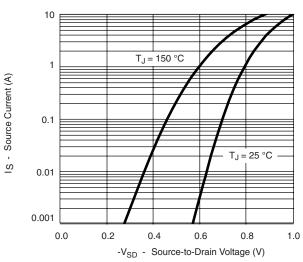


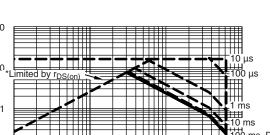
2.3 $V_{GS} = 10 V$ $I_D = 50 A$ 2.0 r_{DS(on)} - On-Resistance (Normalized) 1.7 1.4 1.1 0.8 0.5 - 50 0 25 50 75 100 125 150 175 - 25 T_J - Junction Temperature (°C) **On-Resistance vs. Junction Temperature**

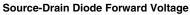
TYPICAL CHARACTERISTICS 25 °C unless noted

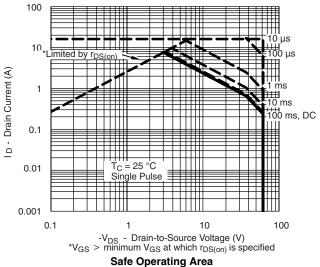




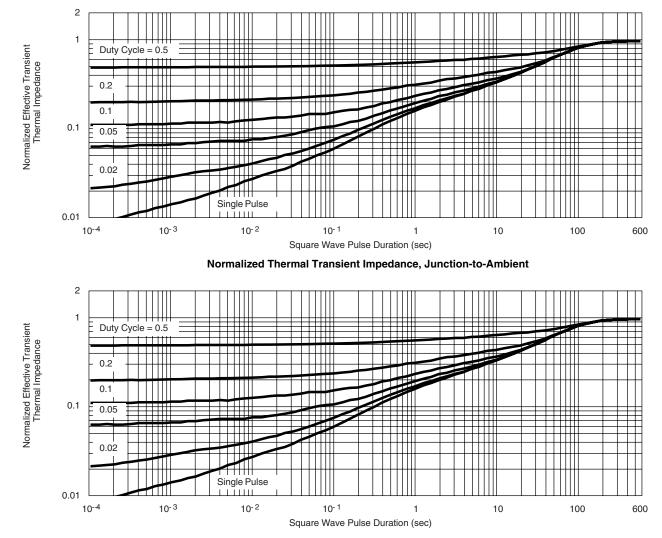










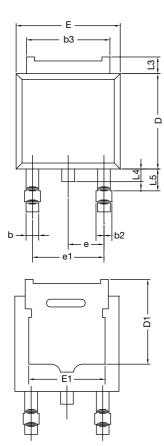


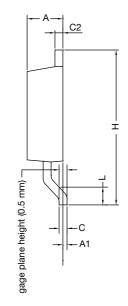
THERMAL RATINGS

Normalized Thermal Transient Impedance, Junction-to-Case



TO-252AA CASE OUTLINE





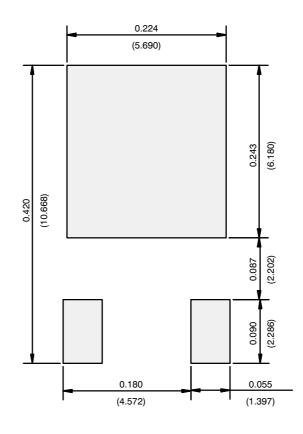
	MILLIMETERS		INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
ECN: X12-(DWG: 5347	0247-Rev. M,	24-Dec-12			

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)



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